

## ESD3Z SERIES

### Transient Voltage Suppressors for ESD Protection

Revision:A

#### General Description

The ESD3Z series is designed to protect voltage sensitive components from ESD and transient voltage events. Excellent clamping capability, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium.

#### Applications

- Cellular Phone Handsets and Accessories
- Microprocessor based equipment
- Personal Digital Assistants(PDA'S)
- Notebooks, Desktops, and Servers
- Portable Instrumentation
- Pagers Peripherals

#### Features

- Small Body Outline Dimensions
- 350 Watts peak pulse power ( $t_p = 8/20\mu s$ )
- Transient protection for data lines to
- Small package for use in portable electronics
- Suitable replacement for MLV's in ESD protection applications
- Protects one I/O or power line
- Low clamping voltage
- Low leakage current
- Solid-state silicon-avalanche technology

#### Complies with the following standards

IEC61000-4-2

Level 4 15 kV (air discharge)

8 kV(contact discharge)

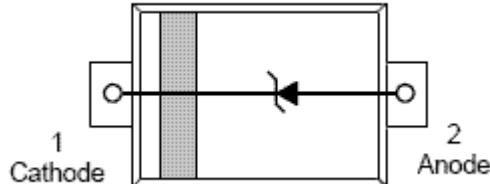
MIL STD 883E - Method 3015-7 Class 3

25 kV HBM (Human Body Model)

#### Functional diagram



SOD-323

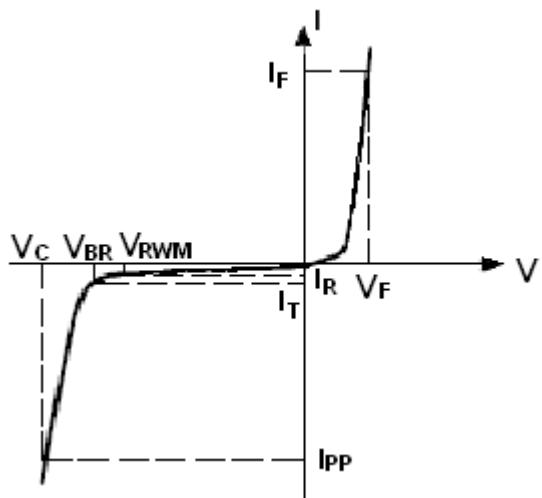


#### Absolute Ratings (Tamb=25°C )

Symbol	Parameter	Value	Units
P <sub>PK</sub>	Peak Pulse Power ( $t_p = 8/20\mu s$ )	350	W
V <sub>ESD</sub>	ESD Voltage(HBM Waveform per IEC 61000-4-2)	8	kV
T <sub>L</sub>	Maximum lead temperature for soldering during 10s	260	°C
T <sub>STG</sub>	Storage Temperature Range	-55 to +150	°C
T <sub>J</sub>	Maximum junction temperature	-55 to +125	°C
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current	24	A

## Electrical Parameter

Symbol	Parameter
$I_{PP}$	Maximum Reverse Peak Pulse Current
$V_C$	Clamping Voltage @ $I_{PP}$
$V_{RWM}$	Working Peak Reverse Voltage
$I_R$	Maximum Reverse Leakage Current @ $V_{RWM}$
$I_T$	Test Current
$V_{BR}$	Breakdown Voltage @ $I_T$
$I_F$	Forward Current
$V_F$	Forward Voltage @ $I_F$



## Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Part Numbers	$V_{BR}$			$I_T$	$V_{RWM}$	$I_R$	$V_F$	$I_F$	C
	Min	Typ	Max				Max.		Typ. (Note1)
	V	V	V	mA	V	$\mu A$	V	mA	pF
ESD3Z5V	6.1	6.7	7.2	1.0	5.0	1	1.25	200	370
ESD3Z12V	13.3	14.0	14.7	1.0	12.0	1	1.25	200	250
ESD3Z15V	16.7	17.4	-	1.0	15.0	1	1.25	200	100

1. Capacitance is measured at  $f=1\text{MHz}$ ,  $V_R=0\text{V}$ ,  $T_A=25^\circ\text{C}$ .

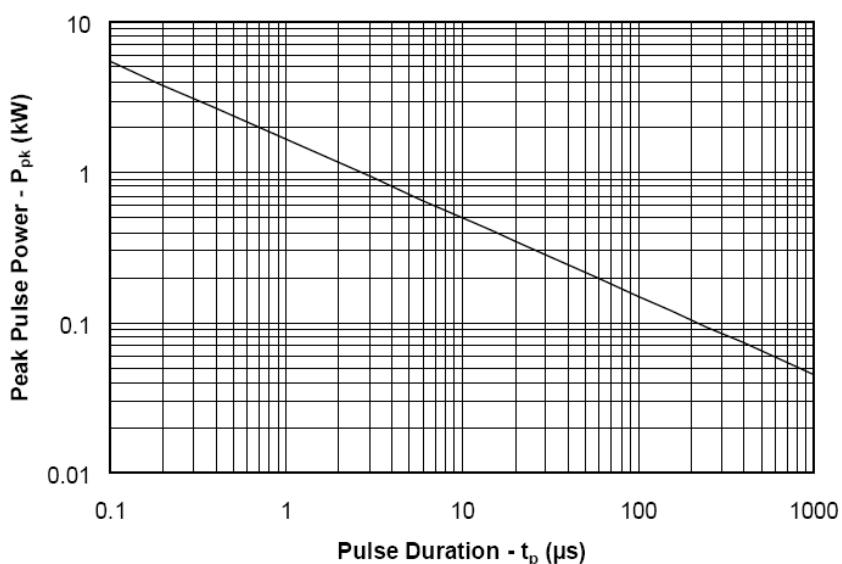
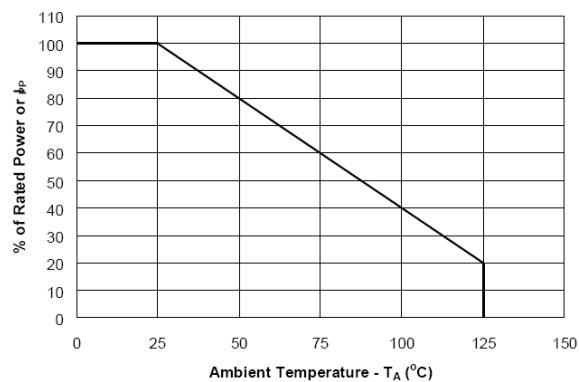
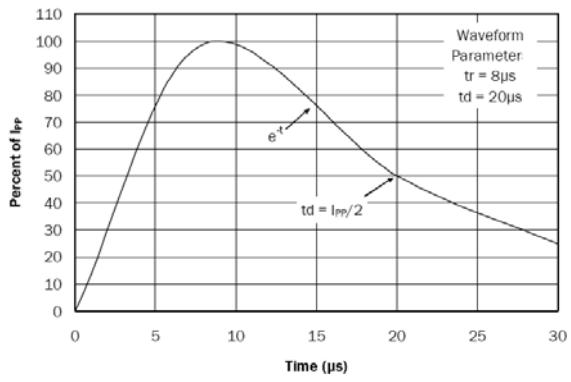


Fig.1 Non-Repetitive Peak Pulse Power vs. Pulse Time

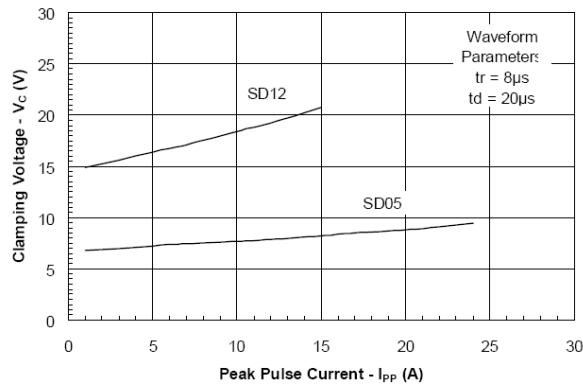
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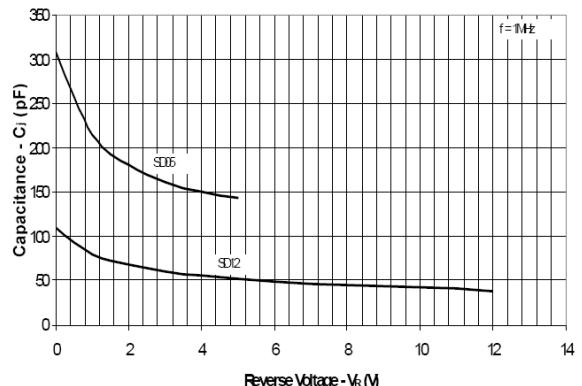
**Fig.2 Power Derating Curve**



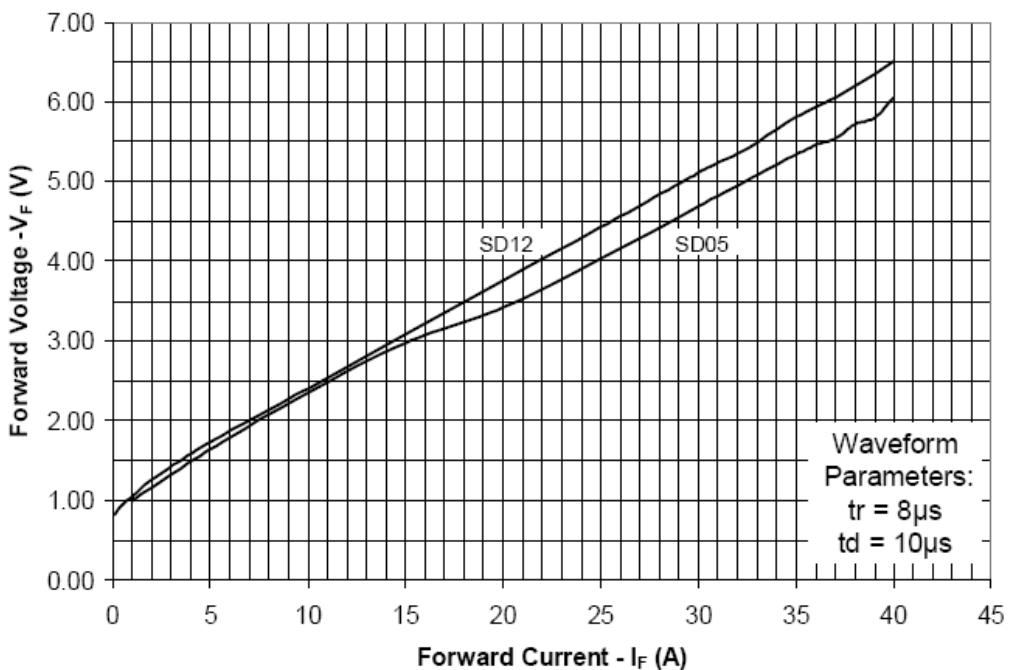
**Fig.3 Waveform**



**Fig.4 Clamping Voltage vs. Peak Pulse Current**



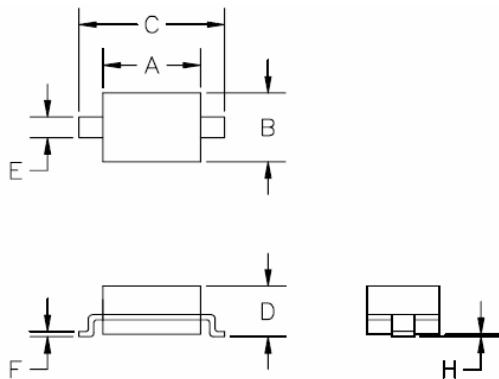
**Fig.5 Capacitance vs. Reverse Voltage**



**Fig.6 Forward Voltage vs. Forward Current**

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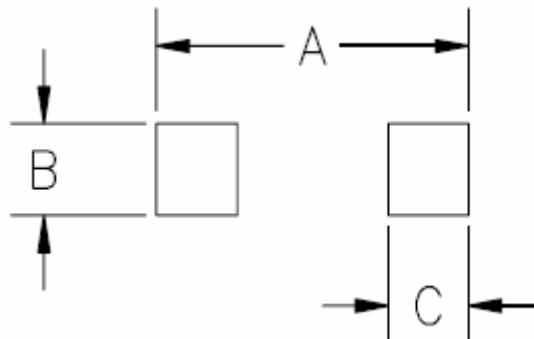
## SOD-323 Mechanical Data



Dim	Dimensions			
	Inches	Millimeters	Min	Max
A	0.060	0.071	1.5	1.8
B	0.045	0.054	1.2	1.4
C	0.060	0.107	2.3	2.7
D	-	0.043	-	1.1
E	0.012	0.016	0.3	0.4
F	0.004	0.010	0.10	0.25
H	-	0.004	-	0.10

**CONTROLLING DIMENSION: MILLIMETERS**

## Land Pattern



RS

Dim	Dimensions			
	Inches	MM	Min	Max
A	-	0.120	-	3.05
B	-	0.031	-	0.8
C	-	0.031	-	0.8

SHANGHAI LEIDITECH ELECTRONICS TECHNOLOGY CO., LTD

Phone: +86- 021-50827201

Email:sale1@leiditech.com

<http://www.leiditech.com>